

YG861S12R (5A)

(120V / 5A)

[0401]

High Voltage Schottky barrier diode

Major characteristics

Characteristics	YG861S12R	Units	Condition
V_{RRM}	120	V	
V_F	0.88	V	$T_c=25^\circ\text{C MAX.}$
I_o	5	A	

Features

- Low V_F
- High Voltage
- Center tap connection

Applications

- High frequency operation
- DC-DC converters
- AC adapter

Maximum ratings and characteristics

- Absolute maximum ratings (at $T_c=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Conditions	Rating	Unit
Repetitive peak surge reverse voltage	V_{RSM}	$tw=500\text{ns}$, duty=1/40	120	V
Repetitive peak reverse voltage	V_{RRM}		120	V
Isolating voltage	V_{iso}	Terminals-to-Case, AC.1min	1500	V
Average output current	I_o	Square wave, duty=1/2 $T_c=104^\circ\text{C}$	5	A
Non-repetitive surge current	I_{FSM}	Sine wave 10ms 1shot	75	A
Operating junction temperature	T_j		+150	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +150	$^\circ\text{C}$

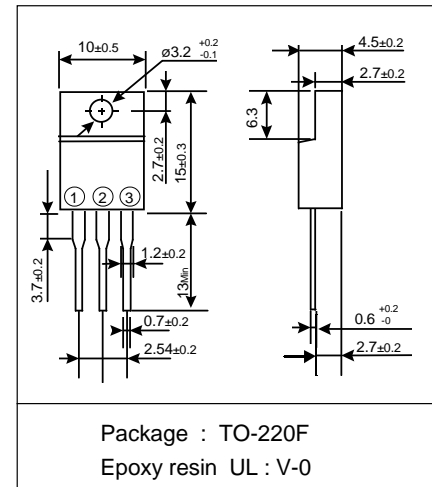
- Electrical characteristics (at $T_c=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V_F	$I_{FM}=10\text{A}$	0.88	V
Reverse current	I_R	$V_R=V_{RRM}$	150	μA
Thermal resistance	$R_{th(j-c)}$	Junction to case	5.0	$^\circ\text{C/W}$

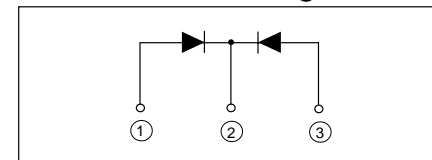
- Mechanical characteristics

Mounting torque	Recommended torque	0.3 to 0.5	N·m
Approximate mass		2	g

Outline drawings, mm

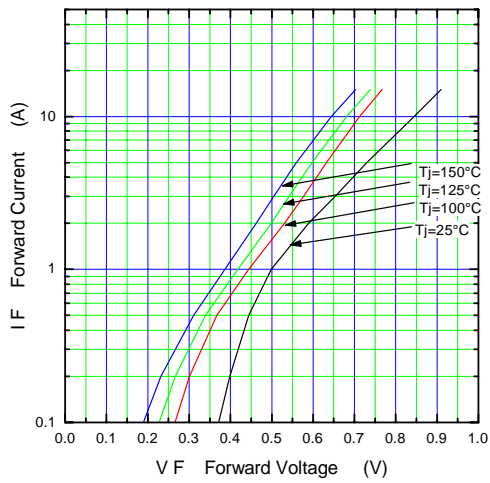


Connection diagram

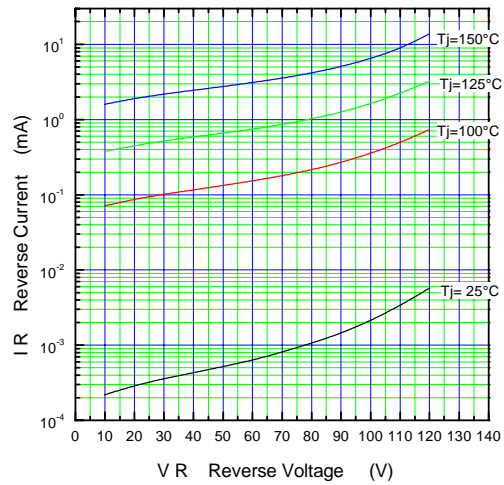


Characteristics

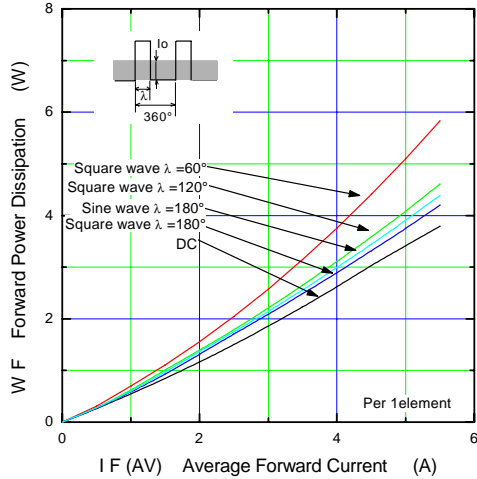
Forward Characteristic (typ.)



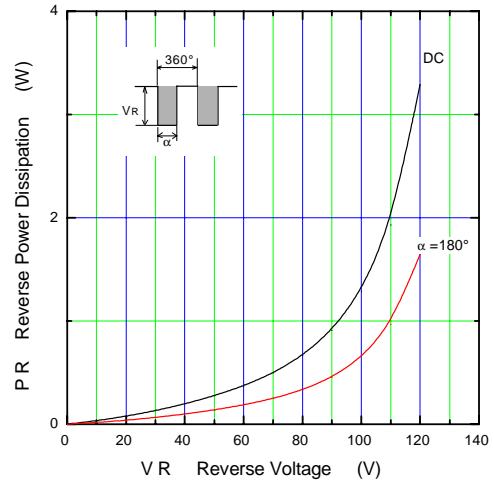
Reverse Characteristic (typ.)



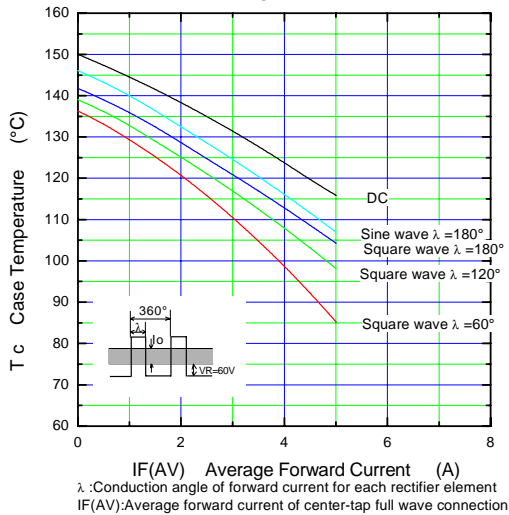
Forward Power Dissipation (max.)



Reverse Power Dissipation (max.)



Current Derating (IF(AV)-Tc) (max.)



Junction Capacitance Characteristic (max.)

